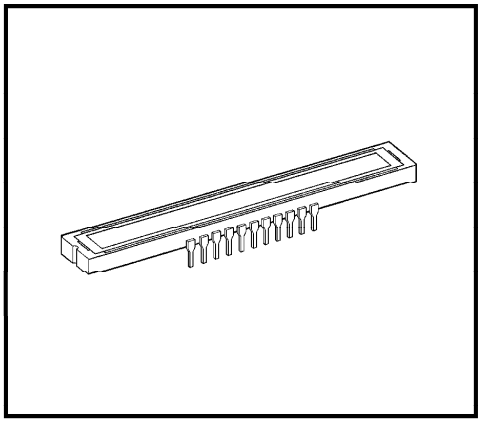
TENTATIVE TOSHIBA CCD LINEAR IMAGE SENSOR CCD(Charge Coupled Device)

TCD1703C

The TCD1703C is a high sensitive and low dark current 7500 elements CCD image sensor.
The sensor is designed for facsimile, imagescanner and OCR.
The device contains a row of 7500 elements photodiodes which provide a 24 lines / mm (600DPI) across a A3 size paper. The device is operated by 5V (pulse), and 12V power supply.



Weight : 6.6g (Typ.)

FEATURES

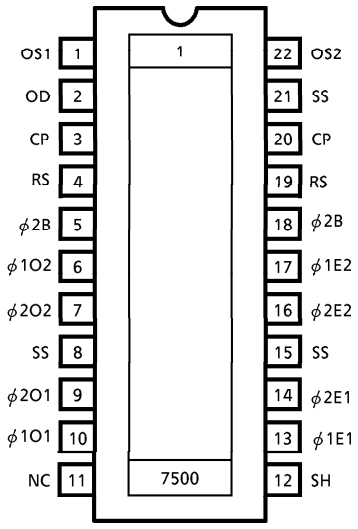
- Number of Image Sensing Elements : 7500 elements
- Image Sensing Element Size
  : 7μm by 7μm on 7μm centers
- Photo Sensing Region : High sensitive and low voltage dark signal pn photodiode
- Clock : 2 phase (5V)
- Package : 22pin DIP

MAXIMUM RATINGS (Note 1)

CHARACTERISTIC	SYMBOL	RATING	UNIT
Clock Pulse Voltage	V_ϕ	−0.3~8	V
Shift Pulse Voltage	V_{SH}		
Reset Pulse Voltage	V_{RS}		
Clamp Pulse Voltage	V_{CP}		
Power Supply Voltage	V_{OD}	−0.3~15	
Operating Temperature	T_{opr}	−25~60	°C
Storage Temperature	T_{stg}	−40~100	°C

(Note 1) All voltage are with respect to SS terminals (Ground).

PIN CONNECTIONS

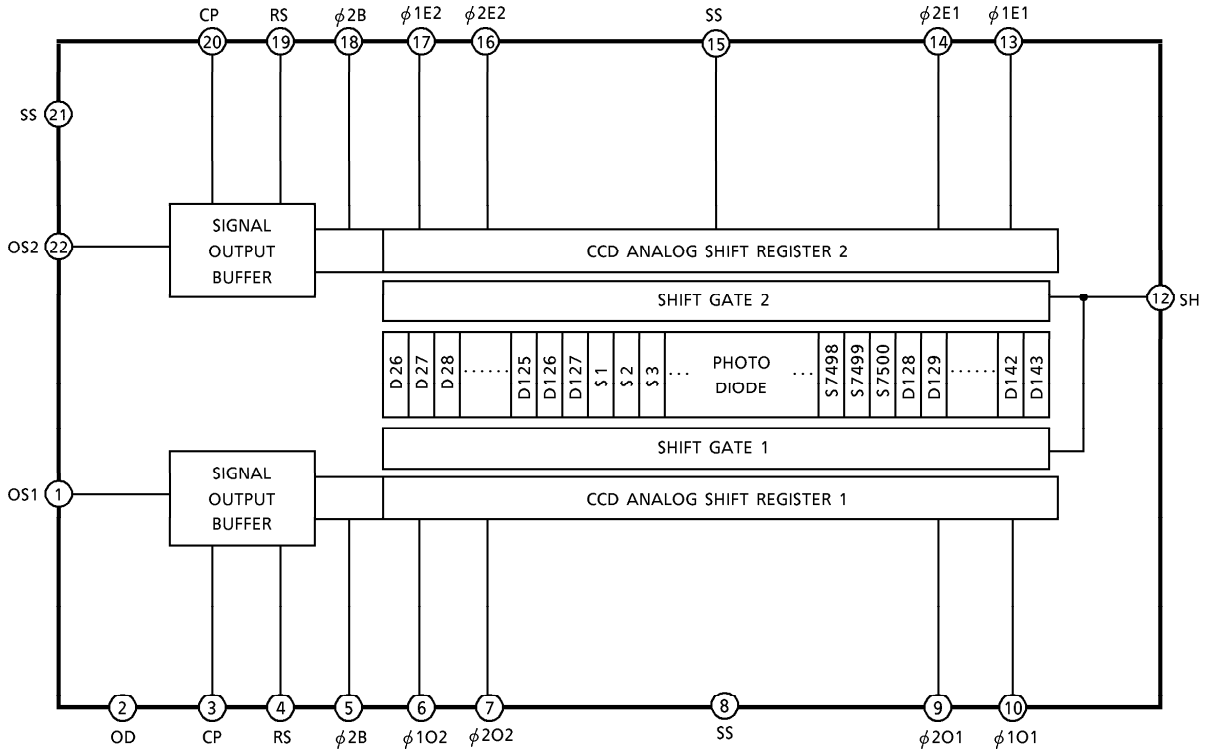


(TOP VIEW)

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CIRCUIT DIAGRAM



PIN NAME

ϕ1E, O	Clock (Phase 1)
ϕ2E, O	Clock (Phase 2)
ϕ2B	Final Stage Clock (Phase 2)
SH	Shift Gate
RS	Reset Gate
CP	Clamp Gate
OS1	Signal Output 1
OS2	Signal Output 2
OD	Power
SS	Ground
NC	Non Connection

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OPTICAL / ELECTRICAL CHARACTERISTICS

(Ta = 25°C, V_{OD} = 12V, $V_\phi = V_{SH} = V_{RS} = V_{CP}$ = 5V (PULSE), f_ϕ = 1MHz,
t_{INT} (INTEGRATION TIME) = 10ms, LIGHT SOURCE = DAYLIGHT FLUORESCENT LAMP,
LOAD RESISTANCE = 100kΩ)

CHARACTERISTIC	SYMBOL	MIN.	TYP.	MAX.	UNIT	NOTE
Sensitivity	R	12	15	18	V / lx·s	
Photo Response Non Uniformity	PRNU	—	3	10	%	(Note 2)
	PRNU (3)	—	6	12	mV	(Note 8)
Saturation Output Voltage	V_{SAT}	1.5	2.0	—	V	(Note 3)
Saturation Exposure	SE	0.08	0.13	—	lx·s	(Note 4)
Dark Signal Voltage	V_{DRK}	—	1.2	3	mV	(Note 5)
Dark Signal Non Uniformity	DSNU	—	2.5	4	mV	(Note 5)
DC Power Dissipation	P_D	—	350	400	mW	
Total Transfer Efficiency	TTE	92	98	—	%	
Output Impedance	Z_o	—	0.2	1	kΩ	
Dynamic Range	DR	—	1660	—	—	(Note 6)
DC Signal Output Voltage	V_{OS1}	4.0	5.5	7.0	V	(Note 7)
	V_{OS2}	4.0	5.5	7.0		
DC Differential Error Voltage	$\lvert V_{OS1}-V_{OS2}\rvert$	—	—	300	mV	
Random Noise	$ND\sigma$	—	1.0	—	mV	(Note 9)

(Note 2) Measured at 50% of SE (Typ.)

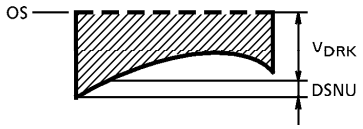
Definition of PRNU : $PRNU = \frac{\Delta\chi}{\overline{\chi}} \times 100\,(\%)$

Where $\overline{\chi}$ is average of total signal outputs and $\Delta\chi$ is maximum deviation from $\overline{\chi}$ under uniform illumination. (Channel 1)
In the case of 3750 elements (Channel 2), the condition is the same as above too.

(Note 3) V_{SAT} is defined as minimum saturation output voltage of all effective pixels.

(Note 4) Definition of SE : $SE = \frac{V_{SAT}}{R}$ (lx·s)

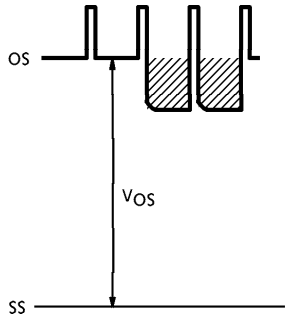
(Note 5) V_{DRK} is defined as average dark signal voltage of all effective pixels.
DSNU is defined as different voltage between V_{DRK} and V_{MDK} when V_{MDK} is maximum dark signal voltage.



(Note 6) Definition of DR : $DR = \frac{V_{SAT}}{V_{DRK}}$

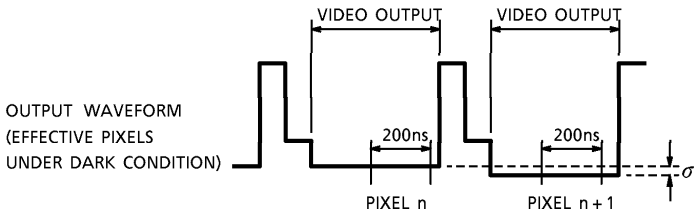
V_{DRK} is proportional to t_{INT} (Integration Time).
So the shorter t_{INT} condition makes wider DR values.

(Note 7) DC signal output voltage and DC compensation output voltage are defined as follows:



(Note 8) PRNU (3) is defined as maximum voltage with next pixel, where measured 5% of SE (Typ.)

(Note 9) Random noise is defined as the standard deviation (sigma) of the output level difference between two adjacent effective pixels under no illumination (i.e. dark condition) calculated by the following procedure.



1) Two adjacent pixels (pixel n and n + 1) in one reading are fixed as measurement points.
2) Each of the output levels at video output periods averaged over 200 nanosecond period to get Vn and Vn + 1.
3) Vn + 1 is subtracted from Vn to get ΔV.

$$\Delta V = Vn - Vn + 1$$

4) The standard deviation of ΔV is calculated after procedure 2) and 3) are repeated 30 times (30 readings).

$$\overline{\Delta V} = \frac{1}{30}\sum_{i=1}^{30} |\Delta Vi| \qquad \sigma = \sqrt{\frac{1}{30}\sum_{i=1}^{30} (|\Delta Vi| - \overline{\Delta V})^2}$$

5) Procedure 2), 3) and 4) are repeated 10 times to get 10 sigma values.

$$\overline{\sigma} = \frac{1}{10}\sum_{j=1}^{10} \sigma j$$

6) $\overline{\sigma}$ value calculated using the above procedure is observed $\sqrt{2}$ times larger than that measured relative to the ground level. So we specify the random noise as follows.

$$\text{Random noise} = \frac{1}{\sqrt{2}}\overline{\sigma}$$

OPERATING CONDITION

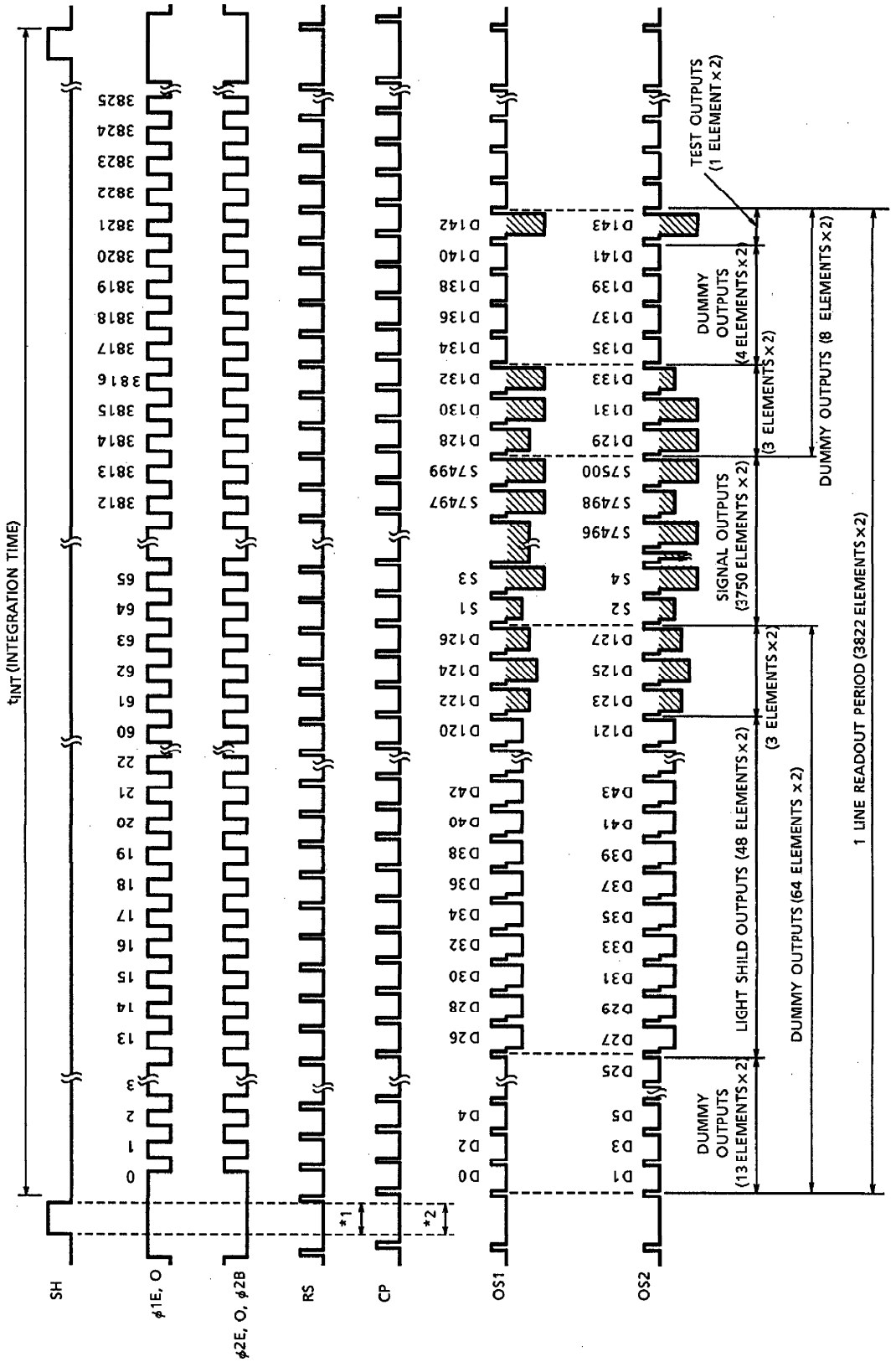
CHARACTERISTIC		SYMBOL	MIN.	TYP.	MAX.	UNIT
Clock Pulse Voltage	"H" Level	$V_{\phi}1E, O$	4.5	5	5.5	V
	"L" Level	$V_{\phi}2E, O$	0	—	0.5	
Final Stage Clock Voltage	"H" Level	$V_{\phi}2B$	4.5	5	5.5	V
	"L" Level		0	—	0.5	
Shift Pulse Voltage	"H" Level	V_{SH}	4.5	5	5.5	V
	"L" Level		0	—	0.5	
Reset Pulse Voltage	"H" Level	V_{RS}	4.5	5	5.5	V
	"L" Level		0	—	0.5	
Clamp Pulse Voltage	"H" Level	V_{CP}	4.5	5	5.5	V
	"L" Level		0	—	0.5	
Power Supply Voltage		V_{OD}	11.4	12.0	13.0	V

CLOCK CHARACTERISTICS (Ta = 25°C)

CHARACTERISTIC		SYMBOL	MIN.	TYP.	MAX.	UNIT
Clock Pulse Frequency		f_{ϕ}	—	1	20	MHz
Reset Pulse Frequency		f_{RS}	—	1	20	MHz
Clock Capacitance	(Note 10)	$C_{\phi}E$	—	300	—	pF
		$C_{\phi}O$	—	300	—	
Final Stage Clock Capacitance		$C_{\phi}B$	—	10	20	pF
Shift Gate Capacitance		C_{SH}	—	60	—	pF
Reset Gate Capacitance		C_{RS}	—	10	20	pF
Clamp Gate Capacitance		C_{CP}	—	10	20	pF

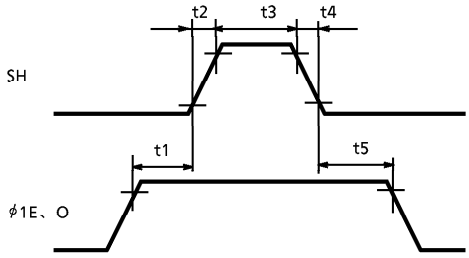
(Note 10) V_{OD} = 12V

TIMING CHART

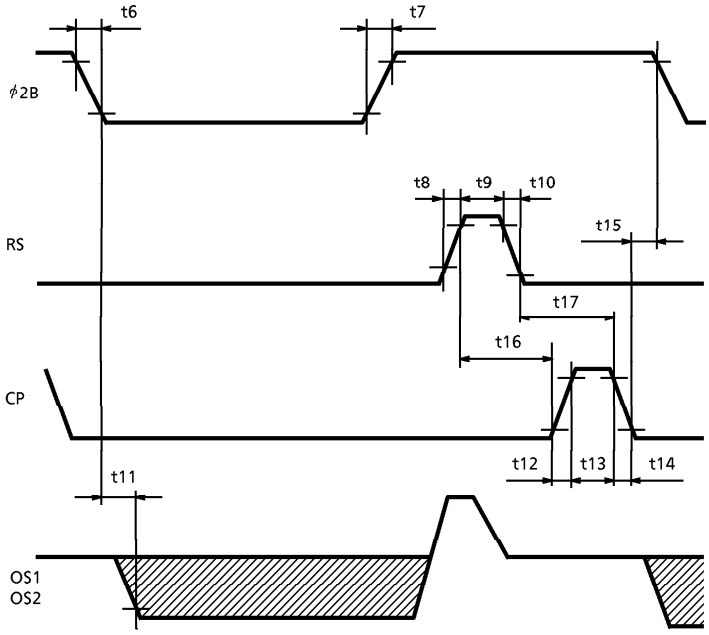


TIMING REQUIREMENTS

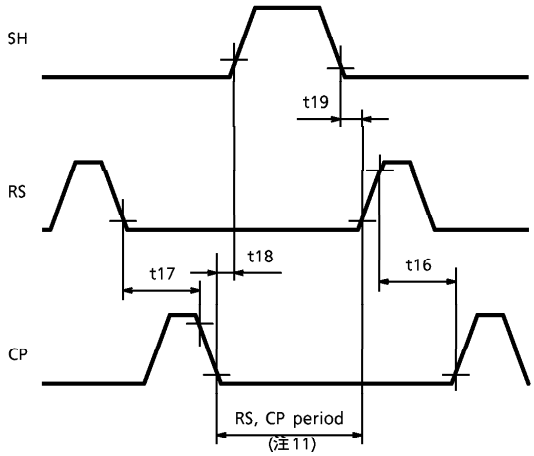
SH, ϕ1 Timing



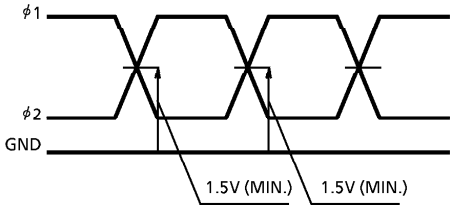
ϕ2, RS, CP, OS Timing



SH, RS, CP Timing



ϕ1, ϕ2 CROSS POINT



(Note 11) Each RS and CP pins put to Low level during this period.

CHARACTERISTIC	SYMBOL	MIN.	TYP. (Note 12)	MAX.	UNIT
Pulse Timing of SH and ϕ1E, ϕ1O	t1, t5	200	500	—	ns
SH Pulse Rise Time, Fall Time	t2, t4	0	50	—	ns
SH Pulse Width	t3	1000	1500	—	ns
ϕ2B Pulse Rise Time, Fall Time	t6, t7	0	100	—	ns
RS Pulse Rise Time, Fall Time	t8, t10	0	20	—	ns
RS Pulse Width	t9	10	100	—	ns
Video Data Delay Time (Note 13)	t11	—	10	—	ns
CP Pulse Rise Time, Fall Time	t12, t14	0	20	—	ns
CP Pulse Width	t13	10	100	—	ns
Pulse Timing of ϕ2B and CP	t15	0	50	—	ns
Pulse Timing of RS and CP	t16	0	100	—	ns
	t17	10	100	—	
Pulse Timing of SH and CP	t18	200	—	—	ns
Pulse Timing of SH and RS	t19	200	—	—	ns

(Note 12) TYP. is the case of f_{RS} = 1.0MHz
(Note 13) Load Resistance is 100kΩ

PRECAUTIONS FOR USE OF CCD IMAGE SENSOR

1. Static Electricity

   This device has some weakly terminals for static electricity. Therefor, please pay attention to treat this device.

   CCD Image Sensor is protected against static electricity, but inferior puncture mode device due to static electricity is sometimes detected. In handling the device, it is necessary to execute the following static electricity preventive measures, in order to prevent the trouble rate increase of the manufacturing system due to static electricity.

   a. Prevent the generation of static electricity due to friction by making the work with bare hands or by putting on cotton gloves and non-charging working clothes.

   b. Discharge the static electricity by providing earth plate or earth wire on the floor, door or stand of the work room.

   c. Ground the tools such as soldering iron, radio cutting plier or pincette.
      It is not necessarily required to execute all precaution items for static electricity.
      It is all right to mitigate the precautions by confirming that the trouble rate within the prescribed range.

2 Window Glass

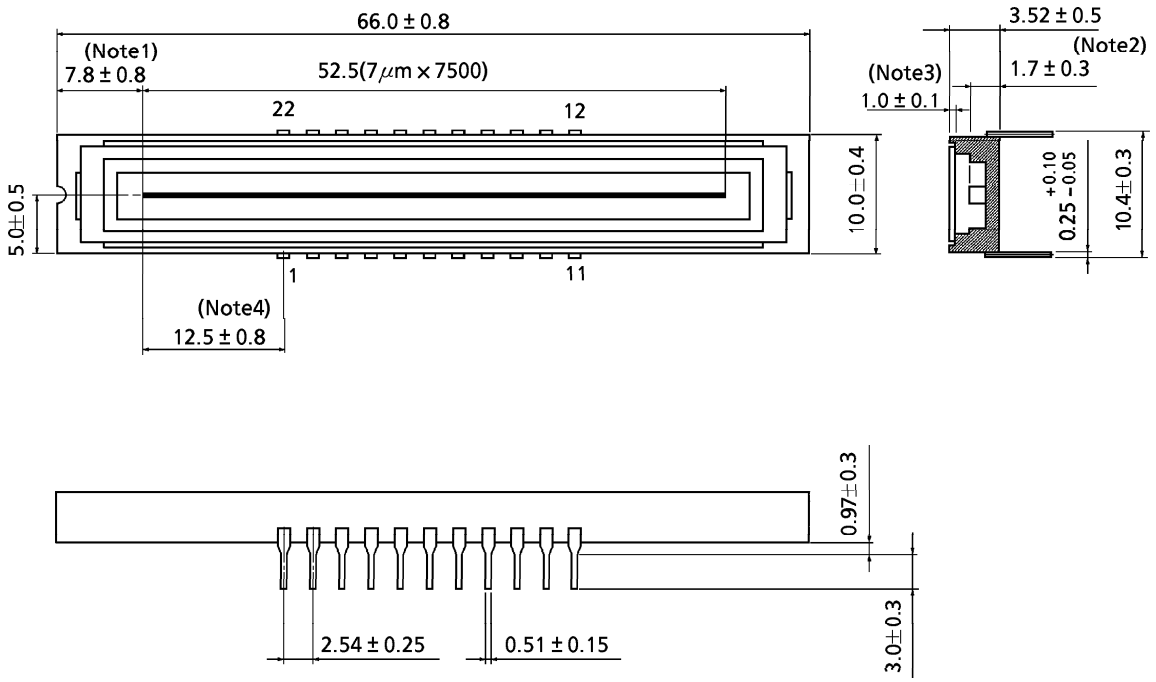
   As the dust and station on the glass window of the package will cause black flow on the picture, never fail to clean the glass surface before using. (Blow compressed vapor, and wipe off the dust, and dirt with soft cloth or paper slightly moistened with alcohol).
   Fully take care for the handling of the device as the window glass will break or a strong friction is given to the window glass surface.

3. Incident Light

   CCD image sensor has sensitivity in a wide range zone of light wave length, but its characteristics will sometimes widely change when used with long wave length input light outside the visual light zone.

OUTLINE DRAWING

Unit in mm



(Note 1) No. 1 SENSOR ELEMENT (S1) TO EDGE OF PACKAGE.
(Note 2) TOP OF CHIP TO BOTTOM OF PACKAGE.
(Note 3) GLASS THICKNES (n = 1.5)
(Note 4) No. 1 SENSOR ELEMENT (S1) TO CENTER OF No. 1 PIN.

Weight : 6.6g (Typ.)